





INSTRUMENTS

SN74LVC3G98 SCLSA08A - MARCH 2024 - REVISED MAY 2024

SN74LVC3G98 Configurable Multiple-Function Gates with Schmitt-Trigger Inputs

1 Features

Texas

- Operating range from 1.1V to 3.6V
- 5.5V tolerant input pins ٠
- Supports standard pinouts •
- Latch-up performance exceeds 250mA per JESD 17
- ESD protection exceeds JESD 22
 - 2000V Human-Body Model (A114-A)
 - 1000V Charged-Device Model (C101)

2 Applications

- Combining power good signals
- Enable digital signals

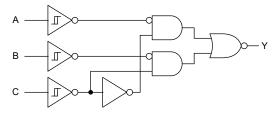
3 Description

The SN74LVC3G98 device features configurable multiple functions with Schmitt-trigger inputs. Eight patterns of a 3-bit input determines the output state. The user can choose the logic functions MUX, AND, OR, NAND, NOR, inverter, and non-inverter.

Package Information

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PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾	BODY SIZE (NOM) ⁽³⁾					
SN74LVC3G98	BQA (WQFN, 14)	3mm × 2.5mm	3mm × 2.5mm					
	PW (TSSOP, 14)	5mm × 6.4mm	5mm × 4.4mm					

- (1) For more information, see Section 11
- (2)The package size (length × width) is a nominal value and includes pins, where applicable
- (3) The body size (length × width) is a nominal value and does not include pins.



Functional Diagram





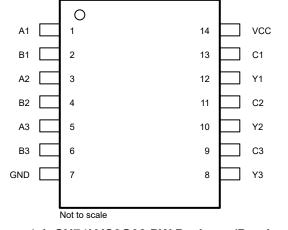
Table of Contents

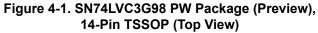
1 Features	1
2 Applications	1
3 Description	1
4 Pin Configuration and Functions	3
5 Specifications	4
5.1 Absolute Maximum Ratings	4
5.2 ESD Ratings	4
5.3 Recommended Operating Conditions	4
5.4 Thermal Information	<mark>5</mark>
5.5 Electrical Characteristics	<mark>5</mark>
5.6 Switching Characteristics	<mark>6</mark>
5.7 Noise Characteristics	<mark>6</mark>
5.8 Typical Characteristics	7
6 Parameter Measurement Information	10
7 Detailed Description	11
7.1 Overview	11
7.2 Functional Block Diagram	
-	

7.3 Feature Description	. 11
7.4 Device Functional Modes	
8 Application and Implementation	. 14
8.1 Application Information	. 14
8.2 Typical Application	. 14
8.3 Power Supply Recommendations	. 16
8.4 Layout	. 16
9 Device and Documentation Support	17
9.1 Documentation Support	. 17
9.2 Receiving Notification of Documentation Updates	17
9.3 Support Resources	. 17
9.4 Trademarks	. 17
9.5 Electrostatic Discharge Caution	17
9.6 Glossary	
10 Revision History	. 17
11 Mechanical, Packaging, and Orderable	
Information	. 17



4 Pin Configuration and Functions





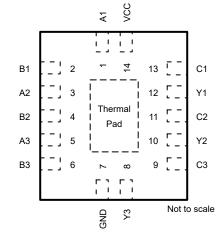


Figure 4-2. SN74LVC3G98 BQA Package, 14-Pin WQFN (Top View)

PIN		TYPE ⁽¹⁾	DESCRIPTION				
NAME	NO.		DESCRIPTION				
A1	1	I	Channel 1, Input A				
B1	2	I	Channel 1, Input B				
A2	3	I	Channel 2, Input A				
B2	4	I	Channel 2, Input B				
A3	5	I	Channel 3, Input A				
В3	6	I	Channel 3, Input B				
GND	7	G	Ground				
Y3	8	0	Channel 3, output Y				
C3	9	I	Channel 3, Input C				
Y2	10	0	Channel 2, Output Y				
C2	11	I	Channel 2, Input C				
Y1	12	0	Channel 1, Output Y				
C1	13	I	Channel 1, Input C				
V _{CC}	14	Р	Positive supply				
Thermal Pad ⁽²)	_	The thermal pad can be connected to GND or left floating. Do not connect to any other signal or supply				

(1) I = input, O = output, I/O = input or output, G = ground, P = power.

(2) BQA package only.



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

				MIN	MAX	UNIT
V _{CC}	Supply voltage range			-0.5	6.5	V
VI	Input voltage range ⁽²⁾	Input voltage range ⁽²⁾		-0.5	6.5	V
Vo	Output voltage range ⁽²⁾		-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0V			-50	mA
Ι _{ΟΚ}	Output clamp current	V _O < 0'	/		-50	mA
I _O	Continuous output current				±50	mA
I _O	Continuous output current through V _{CC} or GND			±100	mA	
TJ	Junction temperature		-65	150	°C	
T _{stg}	Storage temperature			-65	150	°C

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute maximum ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If briefly operating outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.2 ESD Ratings

				VALUE	UNIT	
	Electrostatic	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V		
V _(ESD) discharge	Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	±1000	v			

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

Specifications	Description	Condition	MIN	MAX	UNIT	
V _{CC}	Supply voltage		1.1	3.6	V	
VI	Input voltage			5.5	V	
Vo	Output voltage	(High or low state)		V _{CC}	V	
		V _{CC} = 1.8V		-4		
1	High-level output current	V _{CC} = 2.3V		-8		
I _{OH} F		V _{CC} = 2.7V		-12	mA	
		V _{CC} = 3V		-24		
		V _{CC} = 1.8V		4		
		V _{CC} = 2.3V		8		
OL	Low-level output current	V _{CC} = 2.7V		12	mA	
		V _{CC} = 3V		24		
Δt/Δv	Input transition rise or fall rate			10	ns/V	
T _A	Operating free-air temperature)	-40	125	°C	



5.4 Thermal Information

		Packag	Package Options		
	THERMAL METRIC ⁽¹⁾	PW (TSSOP)	BQA (WQFN)	UNIT	
		14 PINS	14 PINS		
R _{0JA}	Junction-to-ambient thermal resistance	150.8	102.3	°C/W	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	78.3	96.8	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	93.8	70.9	°C/W	
Ψ_{JT}	Junction-to-top characterization parameter	24.7	16.6	°C/W	
Y _{JB}	Junction-to-board characterization parameter	93.2	70.9	°C/W	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	-	50.1	°C/W	

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	-40°C to	UNIT		
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT
V _{T+}	Positive-going input threshold voltage	1.1V	0.5		0.8	V
V _{T+}	Positive-going input threshold voltage	1.5V	0.7		1.11	V
V _{T+}	Positive-going input threshold voltage	1.65V	0.4		1.3	V
V _{T+}	Positive-going input threshold voltage	1.95V	0.6		1.5	V
V _{T+}	Positive-going input threshold voltage	2.3V	0.8		1.7	V
V _{T+}	Positive-going input threshold voltage	2.5V	0.8		1.7	V
V _{T+}	Positive-going input threshold voltage	2.7V	0.8		2	V
V _{T+}	Positive-going input threshold voltage	3V	0.9		2	V
V _{T+}	Positive-going input threshold voltage	3.6V	1.1		2	V
V _{T-}	Negative-going input threshold voltage	1.1V	0.2		0.6	V
V _{T-}	Negative-going input threshold voltage	1.5V	0.34		0.75	V
V _{T-}	Negative-going input threshold voltage	1.65V	0.2		0.9	V
V _{T-}	Negative-going input threshold voltage	1.95V	0.3		1	V
V _{T-}	Negative-going input threshold voltage	2.3V	0.4		1.2	V
V _{T-}	Negative-going input threshold voltage	2.5V	0.4		1.2	V
V _{T-}	Negative-going input threshold voltage	2.7V	0.4		1.4	V
V _{T-}	Negative-going input threshold voltage	3V	0.6		1.5	V
V _{T-}	Negative-going input threshold voltage	3.6V	0.8		1.7	V
ΔV _T	Hysteresis (V _{T+} – V _{T-})	1.1V	0.07		0.53	V
ΔV _T	Hysteresis (V _{T+} – V _{T-})	1.5V	0.18		0.60	V
ΔV _T	Hysteresis (V _{T+} – V _{T-})	1.65V	0.1		1.2	V
ΔV _T	Hysteresis (V _{T+} – V _{T-})	1.95V	0.2		1.3	V
ΔV _T	Hysteresis (V _{T+} – V _{T-})	2.3V	0.3		1.3	V
ΔV _T	Hysteresis (V _{T+} – V _{T-})	2.5V	0.3		1.3	V
ΔV _T	Hysteresis (V _{T+} – V _{T-})	2.7V	0.3		1.1	V
ΔV _T	Hysteresis (V _{T+} – V _{T-})	3V	0.3		1.2	V
ΔV _T	Hysteresis (V _{T+} – V _{T-})	3.6V	0.3		1.2	V
V _{OH}	I _{OH} = -100μA	1.1V to 3.6V	V _{CC} - 0.2			V
V _{OH}	I _{OH} = -4mA	1.65V	1.2			V
V _{OH}	I _{OH} = -8mA	2.3V	1.75			V

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5.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS		-40°C to	UNIT			
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	UNIT	
V _{OH}	L = 10mA	2.7V	2.2			V	
V _{OH}	— I _{OH} = –12mA	3V	2.4			V	
V _{OH}	I _{OH} = –24mA	3V	2.2			V	
V _{OL}	I _{OH} = 100μA	1.1V to 3.6V			0.15	V	
V _{OL}	I _{OH} = 4mA	1.65V			0.45	V	
V _{OL}	I _{OH} = 8mA	2.3V			0.7	V	
V _{OL}	I _{OH} = 12mA	2.7V			0.4	V	
V _{OL}	I _{OH} = 24mA	3V			0.55	V	
I	V _I = V _{CC} or GND	3.6V			±5	μA	
l _{off}	V_1 or $V_0 = V_{CC}$	0V			±10	μA	
I _{cc}	$V_{I} = V_{CC}$ or GND, $I_{O} = 0$	3.6V			40	μA	
ΔI _{CC}	One input at V_{CC} - 0.6V, other inputs at V_{CC} or GND	2.7V to 3.6V			500	μA	
CI	V _I = V _{CC} or GND	3.3V		4.9		pF	
Co	V _O = V _{CC} or GND	3.3V		6.3		pF	
C _{PD}	f = 10MHz	1.8V		31		pF	
C _{PD}	f = 10MHz	2.5V		31		pF	
C _{PD}	f = 10MHz	3.3V		32		pF	

5.6 Switching Characteristics

over operating free-air temperature range; typical values measured at T_A = 25°C (unless otherwise noted). See *Parameter Measurement Information*

PARAMETER	FROM		LOAD CAPACITANCE	V	-40°C to 125°C			UNIT
PARAMETER	(INPUT)	TO (OUTPUT)	LUAD CAPACITANCE	V _{cc}	MIN	TYP	MAX	UNIT
t _{pd}	A, B or C	Y	C _L = 15pF	1.2V ± 0.1V		12	44	ns
t _{pd}	A, B or C	Y	C _L = 15pF	1.5V ± 0.12V		9	15	ns
t _{pd}	A, B or C	Y	C _L = 30pF	1.8V ± 0.15V			10.2	ns
t _{pd}	A, B or C	Y	C _L = 30pF	2.5V ± 0.2V			6.9	ns
t _{pd}	A, B or C	Y	C _L = 50pF	2.7V			6.4	ns
t _{pd}	A, B or C	Y	C _L = 50pF	3.3V ± 0.3V			5.6	ns
t _{sk(o)}				3.3V ± 0.3V			1.5	ns

5.7 Noise Characteristics

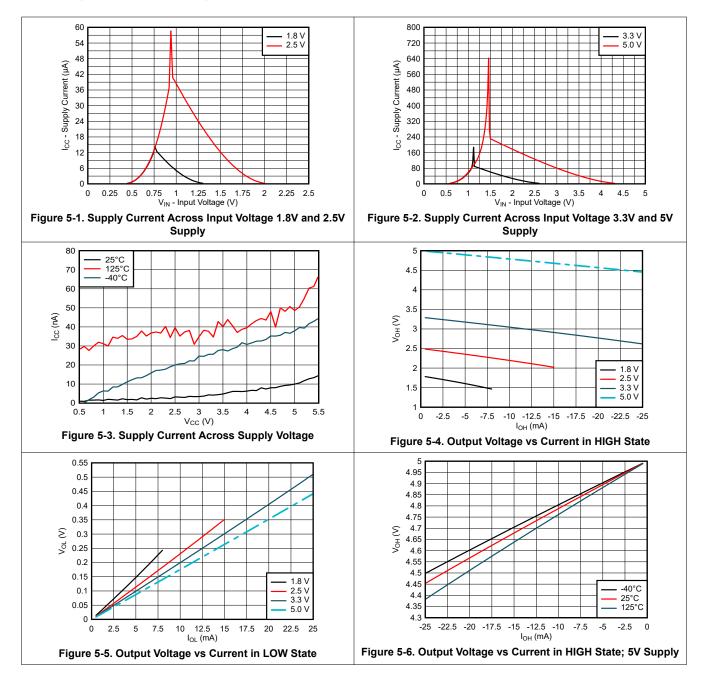
VCC = 3.3V, CL = 50pF, TA = 25°C

, ,					
PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}			0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}	-0.8	-0.3		V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	2.2	3.3		V
V _{IH(D)}	High-level dynamic input voltage	2.0			V
V _{IL(D)}	Low-level dynamic input voltage			0.8	V



5.8 Typical Characteristics

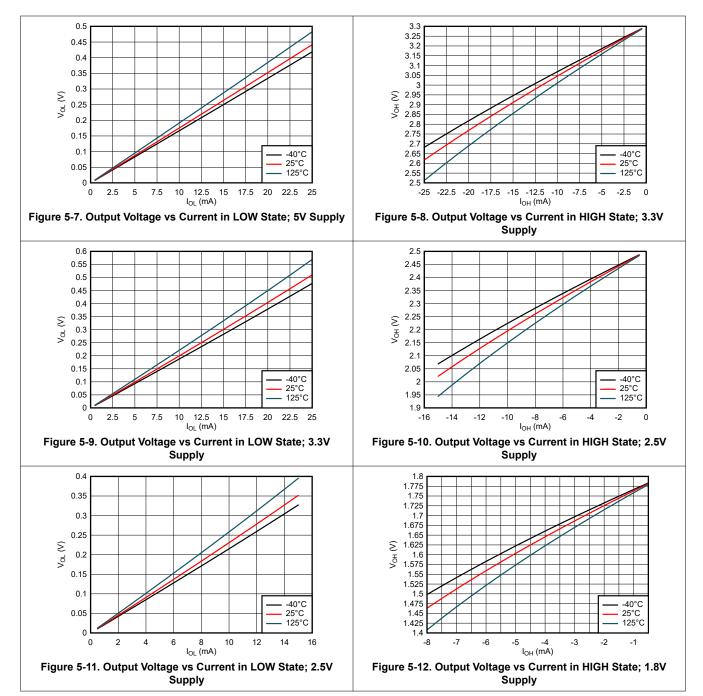
T_A = 25°C (unless otherwise noted)





5.8 Typical Characteristics (continued)

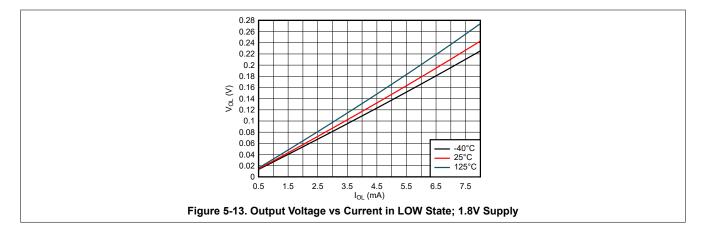
 $T_A = 25^{\circ}C$ (unless otherwise noted)





5.8 Typical Characteristics (continued)

 $T_A = 25^{\circ}C$ (unless otherwise noted)

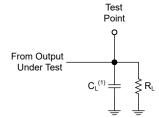


6 Parameter Measurement Information

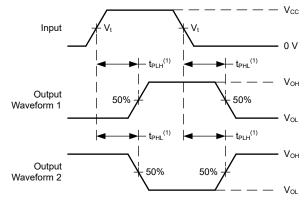
Phase relationships between waveforms were chosen arbitrarily for the examples listed in the following table. All input pulses are supplied by generators having the following characteristics: PRR \leq 1MHz, Z₀ = 50 Ω , t_t \leq 2.5ns.

The outputs are measured individually with one input transition per measurement.

V _{cc}	Vt	RL	CL	ΔV
1.2V ± 0.1V	V _{CC} /2	2kΩ	15pF	0.1V
1.5V ± 0.12V	V _{CC} /2	2kΩ	15pF	0.1V
1.8V ± 0.15V	V _{CC} /2	1kΩ	30pF	0.15V
2.5V ± 0.2V	V _{CC} /2	500Ω	30pF	0.15V
2.7V	1.5V	500Ω	50pF	0.3V
3.3V ± 0.3V	1.5V	500Ω	50pF	0.3V

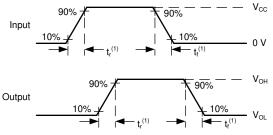


(1) C_L includes probe and test-fixture capacitance. Figure 6-1. Load Circuit for Push-Pull Outputs



(1) The greater between t_{PLH} and t_{PHL} is the same as $t_{\mathsf{pd}}.$

Figure 6-2. Voltage Waveforms Propagation Delays



(1) The greater between t_{r} and t_{f} is the same as $t_{t}. \label{eq:tf}$

Figure 6-3. Voltage Waveforms, Input and Output Transition Times

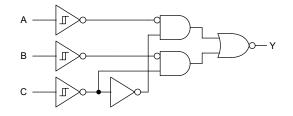


7 Detailed Description

7.1 Overview

The SN74LVC3G98 device features configurable multiple functions with Schmitt-trigger inputs. Eight patterns of a 3-bit input determines the output state. The user can choose the logic functions MUX, AND, OR, NAND, NOR, inverter, and non-inverter.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 CMOS Schmitt-Trigger Inputs

This device includes inputs with the Schmitt-trigger architecture. These inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics* table from the input to ground. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings* table, and the maximum input leakage current, given in the *Electrical Characteristics* table, using Ohm's law ($R = V \div I$).

The Schmitt-trigger input architecture provides hysteresis as defined by ΔV_T in the *Electrical Characteristics* table, which makes this device extremely tolerant to slow or noisy inputs. While the inputs can be driven much slower than standard CMOS inputs, it is still recommended to properly terminate unused inputs. Driving the inputs with slow transitioning signals will increase dynamic current consumption of the device. For additional information regarding Schmitt-trigger inputs, please see *Understanding Schmitt Triggers*.

7.3.2 Balanced CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The drive capability of this device may create fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to over-current. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

The device can drive a load with a total capacitance less than or equal to the maximum load listed in the *Switching Characteristics* - 74 connected to a high-impedance CMOS input while still meeting all of the data sheet specifications. Larger capacitive loads can be applied, however it is not recommended to exceed the provided load value. If larger capacitive loads are required, it is recommended to add a series resistor between the output and the capacitor to limit output current to the values given in the *Absolute Maximum Ratings*.

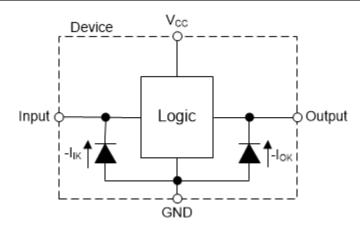
7.3.3 Clamp Diode Structure

Figure 7-1 shows the inputs and outputs to this device have negative clamping diodes only.

CAUTION

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.







7.4 Device Functional Modes

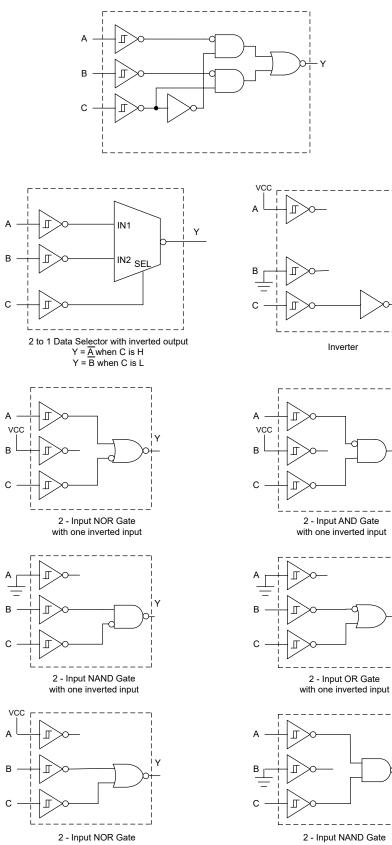
	INPUTS ⁽¹⁾		OUTPUTS
Α	В	С	Y
L	L	L	Н
L	L	Н	Н
L	н	L	L
L	Н	Н	н
Н	L	L	Н
н	L	н	L
н	н	L	L
Н	Н	Н	L

Table 7-1. Function Tab

(1) H = high voltage level, L = low voltage level



7.4.1 Logic Configurations





8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The SN74LVC3G98 device offers flexible configuration for many design applications. This example describes basic power sequencing using the NAND gate configuration. Power sequencing is often used in applications that require a processor or other delicate device with specific voltage timing requirements to protect the device from malfunctioning.

8.2 Typical Application

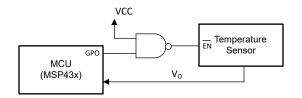


Figure 8-1. Typical Application Schematic

8.2.1 Design Requirements

8.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the electrical characteristics of the device as described in the *Electrical Characteristics* section.

The positive voltage supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74LVC3G98 plus the maximum static supply current, I_{CC} , listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only source as much current that is provided by the positive supply source. Ensure the maximum total current through V_{CC} listed in the *Absolute Maximum Ratings* is not exceeded.

The ground must be capable of sinking current equal to the total current to be sunk by all outputs of the SN74LVC3G98 plus the maximum supply current, I_{CC}, listed in the *Electrical Characteristics*, and any transient current required for switching. The logic device can only sink as much current that can be sunk into its ground connection. Ensure the maximum total current through GND listed in the *Absolute Maximum Ratings* is not exceeded.

The SN74LVC3G98 can drive a load with a total capacitance less than or equal to 50pF while still meeting all of the data sheet specifications. Larger capacitive loads can be applied; however, it is not recommended to exceed 50pF.

The SN74LVC3G98 can drive a load with total resistance described by $R_L \ge V_O / I_O$, with the output voltage and current defined in the *Electrical Characteristics* table with V_{OH} and V_{OL} . When outputting in the HIGH state, the output voltage in the equation is defined as the difference between the measured output voltage and the supply voltage at the V_{CC} pin.

Total power consumption can be calculated using the information provided in the CMOS Power Consumption and Cpd Calculation application note.

Thermal increase can be calculated using the information provided in the *Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices* application note.



CAUTION

The maximum junction temperature, $T_{J(max)}$ listed in the *Absolute Maximum Ratings*, is an additional limitation to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

8.2.1.2 Input Considerations

Input signals must cross $V_{t-(min)}$ to be considered a logic LOW, and $V_{t+(max)}$ to be considered a logic HIGH. Do not exceed the maximum input voltage range found in the *Absolute Maximum Ratings*.

Unused inputs must be terminated to either V_{CC} or ground. The unused inputs can be directly terminated if the input is completely unused, or they can be connected with a pullup or pulldown resistor if the input will be used sometimes, but not always. A pullup resistor is used for a default state of HIGH, and a pulldown resistor is used for a default state of LOW. The drive current of the controller, leakage current into the SN74LVC3G98 (as specified in the *Electrical Characteristics*), and the desired input transition rate limits the resistor size. A 10-k Ω resistor value is often used due to these factors.

The SN74LVC3G98 has no input signal transition rate requirements because it has Schmitt-trigger inputs.

Another benefit to having Schmitt-trigger inputs is the ability to reject noise. Noise with a large enough amplitude can still cause issues. To know how much noise is too much, please refer to the $\Delta V_{T(min)}$ in the *Electrical Characteristics*. This hysteresis value will provide the peak-to-peak limit.

Unlike what happens with standard CMOS inputs, Schmitt-trigger inputs can be held at any valid value without causing huge increases in power consumption. The typical additional current caused by holding an input at a value other than V_{CC} or ground is plotted in the *Typical Characteristics*.

Refer to the *Feature Description* section for additional information regarding the inputs for this device.

8.2.1.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the V_{OH} specification in the *Electrical Characteristics*. The ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the V_{OL} specification in the *Electrical Characteristics*.

Push-pull outputs that could be in opposite states, even for a very short time period, should never be connected directly together. This can cause excessive current and damage to the device.

Two channels within the same device with the same input signals can be connected in parallel for additional output drive strength.

Unused outputs can be left floating. Do not connect outputs directly to V_{CC} or ground.

Refer to the Feature Description section for additional information regarding the outputs for this device.

8.2.2 Detailed Design Procedure

- 1. Add a decoupling capacitor from V_{CC} to GND. The capacitor needs to be placed physically close to the device and electrically close to both the V_{CC} and GND pins. An example layout is shown in the *Layout Example* section.
- Ensure the capacitive load at the output is ≤ 70pF. This is not a hard limit; by design, however, it will
 optimize performance. This can be accomplished by providing short, appropriately sized traces from the
 SN74LVC3G98 to the receiving device.
- 3. Ensure the resistive load at the output is larger than $(V_{CC} / I_O(max)) \Omega$. Doing so prevents the maximum output current in the *Absolute Maximum Ratings* from being violated. Most CMOS inputs have a resistive load measured in mega ohms; much larger than the minimum calculated previously.
- 4. Thermal issues are rarely a concern for logic gates, however the power consumption and thermal increase can be calculated using the steps provided in the application report, *CMOS Power Consumption and Cpd Calculation*

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8.2.3 Application Curves

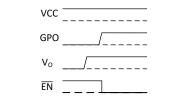


Figure 8-2. Typical Application Timing Diagram

8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a bypass capacitor to prevent power disturbance. A 0.1µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1µF and 1µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in Figure 8-3.

8.4 Layout

8.4.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.

8.4.2 Layout Example

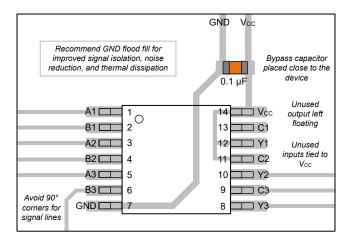


Figure 8-3. Example Layout for the SN74LVC3G98



9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, CMOS Power Consumption and Cpd Calculation application note
- Texas Instruments, *Designing With Logic* application note
- Texas Instruments, Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices application note
- Texas Instruments, Implications of Slow or Floating CMOS Inputs application note

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.4 Trademarks

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

С	hanges from Revision * (March 2024) to Revision A (May 2024)	Page
•	Removed preview packages note from Package Information table	1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC3G98BQAR	ACTIVE	WQFN	BQA	14	3000	RoHS & Green	(6) NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC398A	Samples
SN74LVC3G98PWR	ACTIVE	TSSOP	PW	14	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(LVC3G98, LVC3G98A)	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LVC3G98 :

Automotive : SN74LVC3G98-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC3G98BQAR	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1
SN74LVC3G98PWR	TSSOP	PW	14	3000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC3G98PWR	TSSOP	PW	14	3000	330.0	12.4	6.85	5.45	1.6	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

16-May-2024



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC3G98BQAR	WQFN	BQA	14	3000	210.0	185.0	35.0
SN74LVC3G98PWR	TSSOP	PW	14	3000	356.0	356.0	35.0
SN74LVC3G98PWR	TSSOP	PW	14	3000	366.0	364.0	50.0

BQA 14

2.5 x 3, 0.5 mm pitch

GENERIC PACKAGE VIEW

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





BQA0014A

PACKAGE OUTLINE

WQFN - 0.8 mm max height

PLASTIC QUAD FLAT PACK-NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



BQA0014A

EXAMPLE BOARD LAYOUT

WQFN - 0.8 mm max height

PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



BQA0014A

EXAMPLE STENCIL DESIGN

WQFN - 0.8 mm max height

PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



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